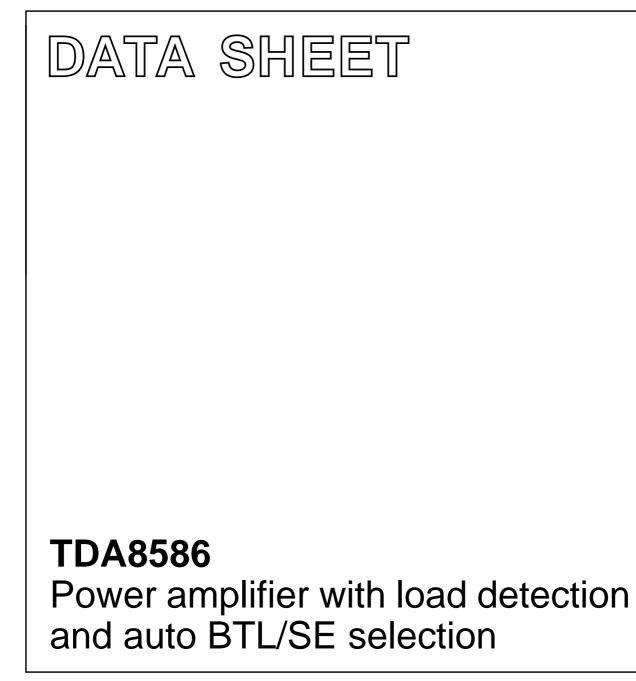
INTEGRATED CIRCUITS



Preliminary specification Supersedes data of 1999 Apr 08 File under Integrated Circuits, IC01 2001 Jul 23





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HILIP

Preliminary specification

Power amplifier with load detection and auto BTL/SE selection

TDA8586

FEATURES

General

- Operating voltage from 8 to 18 V
- · Low distortion
- · Few external components, fixed gain
- Automatic mode selection (SE or BTL) depending on connected rear loads
- Can be used as a stereo amplifier in Bridge-Tied Load (BTL) or quad Single-Ended (SE) amplifiers
- · Single-ended mode without loudspeaker capacitor
- Soft clipping, to guarantee good clip behaviour with inductive loads
- · Mute and standby mode with one-pin operation
- Diagnostic information for Dynamic Distortion Detector (DDD), high temperature (140 °C) operation mode and short-circuit
- No switch-on/off plops when switching between standby and mute and from mute to on
- Load detection on rear channels when switching from standby to mute
- Fast mute on supply voltage drops (low V_P mute).

Protection

- Short-circuit proof to ground, positive supply voltage on all pins and across load
- ESD protected on all pins
- Thermal protection against temperatures exceeding 150 $^{\circ}\text{C}$
- Load dump protection
- Overvoltage protection.

ORDERING INFORMATION

PACKAGENUMBERNAMEDESCRIPTIONVERSIONTDA8586QDBS17Pplastic DIL-bent-SIL power package; 17 leads (lead length 12 mm)SOT243-1TDA8586THHSOP20heatsink small outline package; 20 leads; low stand-offSOT418-2

start-up.

This amplifier is protected for all general short-circuit conditions to battery or ground, overvoltage, 45 V load dump and short-circuits on the speaker outputs.

The device incorporates the following functions:

Automatic switching between 2 and 4 speaker

• 4 × 6 W SE amplifies without SE capacitor, because of

the availability of 2 half supply voltage power buffers

operation. The mode of operation is determined during

The device is contained in a 20-pin power HSOP package, but is also available in a 17-pin SIL power package. When packaged in the 20-pin HSOP package additional functions are available:

DDD level selection between 2 and 10%

GENERAL DESCRIPTION

• 2 × 20 W BTL amplifiers

• Overrule pin for changing mode of operation (from SE to BTL or from BTL to SE).

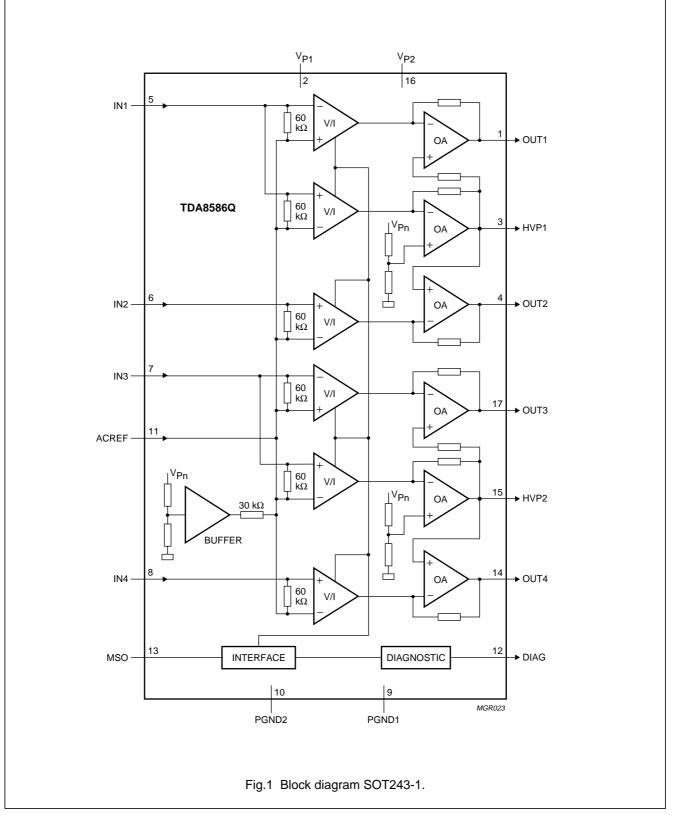
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QUICK REFERENCE DATA

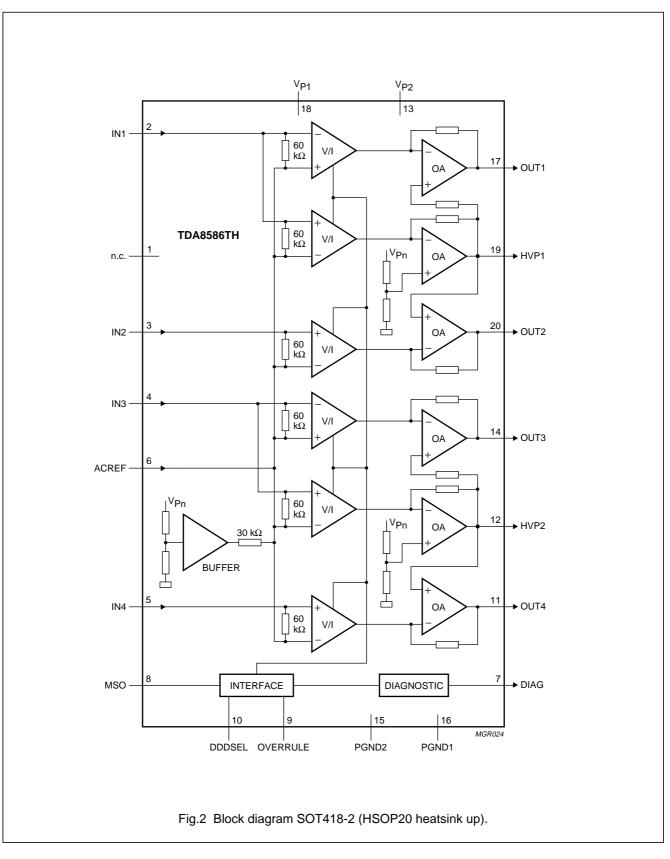
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
VP	operating supply voltage		8.0	_	18	V
I _{q(tot)}	total quiescent current	V _P = 14.4 V, SE mode	-	140	170	mA
I _{stb}	standby supply current	V _P = 14.4 V	-	1	100	μA
G _v	voltage gain	SE mode	25	26	27	dB
		BTL mode	31	32	33	dB
Bridge-tied I	oad application					
Po	output power	$V_{P} = 14.4 \text{ V}; \text{ R}_{L} = 4 \Omega$				
		THD = 0.5%	14	15	_	W
		THD = 10%	17	21	_	W
THD	total harmonic distortion	$ f_i = 1 \text{ kHz}; P_o = 1 \text{ W}; V_P = 14.4 \text{ V}; R_L = 4 \Omega $	-	0.05	0.15	%
V _{OO}	DC output offset voltage	$V_P = 14.4 \text{ V}; \text{ R}_L = 4 \Omega;$ mute condition	-	10	20	mV
		$V_P = 14.4 \text{ V}$; on condition	-	0	100	mV
V _{n(o)}	noise output voltage	$R_{s} = 1 \text{ k}\Omega; V_{P} = 14.4 \text{ V}$	-	100	200	μV
Single-ende	d application	•			•	•
Po	output power	$V_{P} = 14.4 \text{ V}; \text{ R}_{L} = 4 \Omega$				
		THD = 0.5%	4	4.5	_	w
		THD = 10%	5	6	_	w
THD	total harmonic distortion	$f_i = 1 \text{ kHz}; P_o = 1 \text{ W};$ $V_P = 14.4 \text{ V}; R_L = 4 \Omega$	-	0.08	0.15	%
V _{OO}	DC output offset voltage	$V_P = 14.4 \text{ V}; \text{ R}_L = 4 \Omega;$ mute condition	-	10	20	mV
		$V_P = 14.4 V$; on condition	-	0	100	mV
V _{n(o)}	noise output voltage	$R_{s} = 1 k\Omega; V_{P} = 14.4 V$	-	80	150	μV

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BLOCK DIAGRAM



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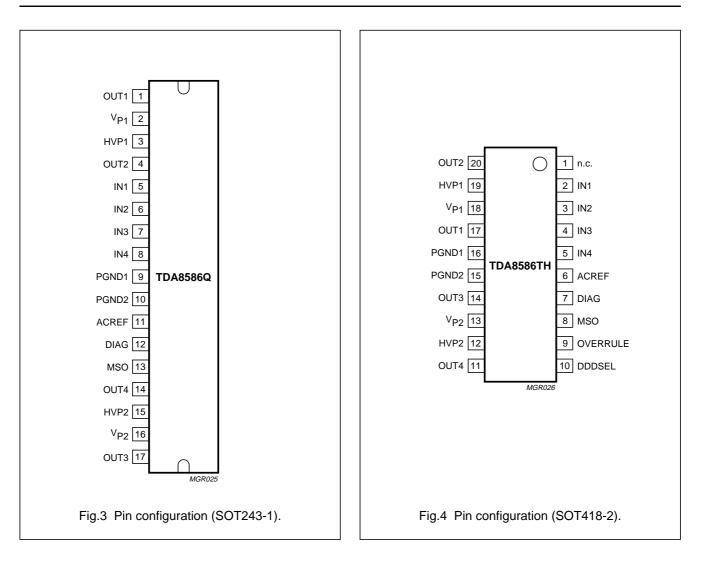


TDA8586

Power amplifier with load detection and auto BTL/SE selection

PINNING

	P	IN	DECODIDITION	
SYMBOL	TDA8586Q	TDA8586TH	DESCRIPTION	
n.c.	-	1	not connected	
IN1	5	2	non-inverting input 1	
IN2	6	3	inverting input 2	
IN3	7	4	non inverting input 3	
IN4	8	5	inverting input 4	
ACREF	11	6	common signal input	
DIAG	12	7	diagnostic output/mode fix	
MSO	13	8	mode select mute, standby or on	
OVERRULE	_	9	mode selection overrule	
DDDSEL	-	10	2 or 10% dynamic distortion detection	
OUT4	14	11	SE output 4 (negative)	
HVP2	15	12	buffer output/BTL output 2 (negative)	
V _{P2}	16	13	supply voltage 2	
OUT3	17	14	SE output 3/BTL output 2 (positive)	
PGND2	10	15	power ground 2	
PGND1	9	16	power ground 1	
OUT1	1	17	SE output 1/BTL output 1 (positive)	
V _{P1}	2	18	supply voltage 1	
HVP1	3	19	buffer output/BTL output 1 (negative)	
OUT2	4	20	SE output 2 (negative)	



TDA8586

Power amplifier with load detection and auto BTL/SE selection

FUNCTIONAL DESCRIPTION

The TDA8586 is a multi-purpose power amplifier with four amplifiers and 2 buffer stages, which can be connected in the following configurations with high output power and low distortion:

- Dual Bridge-Tied Load (BTL) amplifiers
- Quad Single-Ended (SE) amplifiers.

In the BTL mode of operation, the 2 buffer amplifiers act as inverting amplifiers to complete the bridge across the front amplifiers (OUT1 and OUT3) and the rear outputs (OUT2 and OUT4) enter a high-impedance state.

In the SE mode of operation, the buffers act as an AC ground path thereby eliminating the need for series capacitors on the speaker outputs.

Diagnostics:

- While the IC is in the mute mode, the diagnostic output will signal the mode of operation when the IC is not overruled
- In the on mode the diagnostic output will signal any fault in the IC or if the output of any amplifier is clipping with a distortion of 10% (or 2% depending on selected clip-mode).

Special attention is given to the dynamic behaviour as follows:

- Noise suppression during engine start
- No plops when switching from standby to on
- Slow offset change between mute and on (controlled by MSO pin)
- Low noise levels, which are independent of the supply voltage.

Protections are included to avoid the IC being damaged at:

- Over temperature: T_i > 150 °C
- Short-circuit of the output pin(s) to ground or supply rail. When short-circuited, the power dissipation is limited
- ESD protection (Human Body Model 3000 V and Machine Model 300 V).

The presence of the load is measured after the transition between standby and mute. The IC will determine if there is an acceptable load on both outputs (OUT2 and OUT4). If both outputs are unloaded, the IC will switch to a 2 speaker mode of operation (BTL mode), unless it is overruled.

There are two options to overrule:

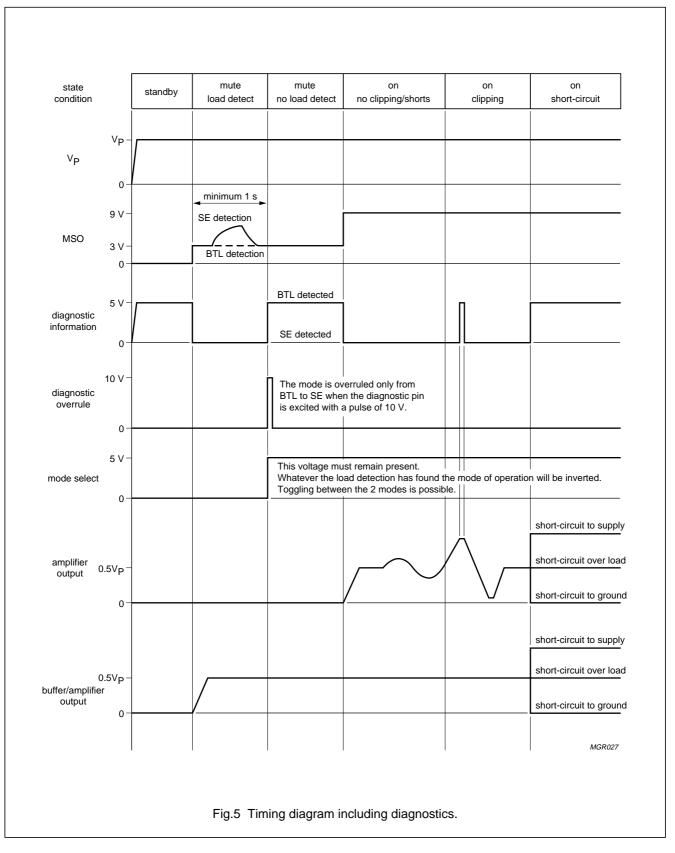
- Before transition from mute to on, after a load detection, pulling the diagnostic output above 9.5 V will force the IC into 4 speaker mode
- 2. TDA8586TH: pulling the OVERRULE pin according pinning table.

Care should be taken with the OVERRULE function as it works during the on mode. If there is a 2 or 4 speaker mode change during the on mode a large plop can be heard on the speakers.

The ACREF input (common signal input) acts with the four signal inputs (IN1 to IN4) to provide quasi differential inputs. A capacitor must be connected to this pin of which the ground pin should be connected to the ground at the signal source (usually the ground at the audio signal processor). This capacitor has a dual function. During the speaker detection, the signal ground capacitor is used to set the time constant of the measurement (and thus determines the minimum required switch-on time). The capacitor on the MSO pin allows the integrate function to provide immunity to outside noises during load detection.

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Power amplifier with load detection and auto BTL/SE selection



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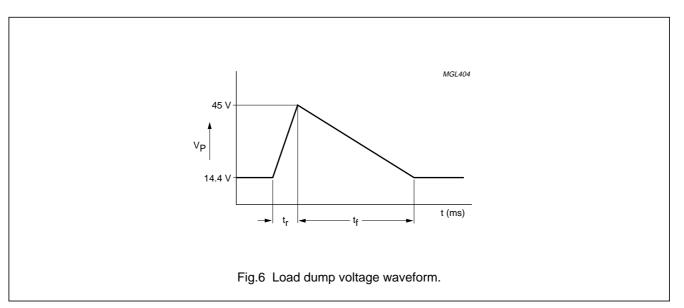
LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _P	supply voltage	operating	8	18	V
		load dump protected; see Fig.6	-	45	V
V _{DIAG}	voltage on diagnostic pin		-	18	V
I _{OSM}	non-repetitive peak output current		-	6	A
I _{ORM}	repetitive peak output current		-	4	А
V _{rp}	reverse polarity voltage	note 1	-	6	V
V _{sc}	AC and DC short-circuit voltage of output pins across loads and to ground or supply pins		-	18	V
P _{tot}	total power dissipation		-	75	W
Tj	junction temperature		_	150	°C
T _{stg}	storage temperature		-55	+150	°C
T _{amb}	operating ambient temperature		-40	+150	°C

Note

1. A large reverse current will flow, therefore external protection is needed (fuse and reverse diode).



THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	40	K/W
R _{th(j-c)}	thermal resistance from junction to case		2	K/W

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CHARACTERISTICS

 V_P = 14.4 V; T_{amb} = 25 °C; f_i = 1 kHz; R_L = ∞ ; measured in test circuit of Fig.8; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Supplies			-	-	-	-1
V _P	operating supply voltage		8.0	14.4	18	V
I _{q(tot)}	total quiescent current	SE mode	-	140	170	mA
I _{stb}	standby current		-	1	100	μA
Vo	DC output voltage	V _P = 14.4 V	-	7.0	_	V
V _{P(mute)}	low supply voltage mute		6.0	7.0	8.0	V
Vo	single-ended and bridge-tied load output voltage	$V_P = 14.4 \text{ V}; \text{ R}_L = 4 \Omega$ mute condition	_	_	20	mV
		on condition	_	_	100	mV
VI	DC input voltage	V _P = 14.4 V	-	4.0	_	V
PIN MSO						1
V _{MSO}	voltage at pin MSO	standby condition	0	_	0.8	V
Mee		mute condition; note 1	2.0	3.0	4	V
		on condition	8.0	_	10.5	V
I _{MSO}	input current	mute pin at standby condition; V _{MSO} < 0.8 V	-	5	40	μA
Diagnostic	; output buffer (open-collector)	; see Figs 7 to 8				
V _{DIAG(L)}	diagnostic output voltage LOW	I _{sink} = 1 mA	_	0.3	0.8	V
ILI	leakage current	V _{DIAG} = 14.4 V	-	-	1	μA
V _{DIAG(or)}	diagnostic override voltage	in mute mode after load detection	10.5	-	18	V
V _{DIAG(4ch)}	diagnostic 4 channel indication voltage	mute, after load detection with 4 speakers connected	-	0.3	0.8	V
CD2	clip detector LOW	THD mode; $V_{DIAG} > 3 V$; R = 10 k Ω	0.5	2	3.5	%
CD10	clip detector HIGH	THD mode (default); V _{DIAG} > 3 V; R = 10 k Ω	7	10	13	%
CLIP DETECT	CONTROL PIN		-	•		1
V _{DDDSEL}	voltage at DDD select pin to	10% DDD	0	_	1	V
-	obtain:	2% DDD	3	_	6	V
IDDDSEL	Input current DDD select pin	V _{DDDSEL} = 5 V	15	-	140	μA
Stereo BTL	application (see Fig.7)		-	•		
THD	total harmonic distortion	$f_i = 1 \text{ kHz}; P_o = 1 \text{ W}; R_L = 4 \Omega$	-	0.05	0.15	%
		$\begin{array}{l} 45 \text{ Hz} < f_i < 10 \text{ kHz}; \text{ P}_o = 1 \text{ W}; \\ \text{R}_L = 4 \Omega; \text{ filter: } \text{f} < 30 \text{ kHz} \end{array}$	-	0.3	-	%
Po	output power	$V_{P} = 14.4 \text{ V}; \text{ R}_{L} = 4 \Omega; \text{ note } 2$				
		THD = 0.5%	14	15	_	W
		THD = 10%	17	21	_	w

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _v	voltage gain	V _{i(rms)} = 15 mV	31	32	33	dB
ΔG_v	channel unbalance	V _{i(rms)} = 15 mV	-0.7	0	+0.7	dB
α _{cs}	channel separation	$P_{o} = 2$ W; f _i = 1 kHz; R _L = 4 Ω	45	55	_	dB
V _{OO}	DC output offset voltage	$V_P = 14.4 V$; on condition	-	0	100	mV
		$V_P = 14.4 \text{ V}; \text{ R}_L = 4 \Omega;$ mute condition	_	10	20	mV
V _{n(o)}	noise output voltage on	$R_s = 1 \text{ k}\Omega; V_P = 14.4 \text{ V}; \text{ note } 3$	-	100	150	μV
V _{n(o)(mute)}	noise output voltage mute	note 3	-	0	20	μV
V _{o(mute)}	output voltage mute	V _{i(rms)} = 1 V	-	3	500	μV
SVRR	supply voltage ripple rejection:					
		on condition	45	55	-	dB
		mute condition	55	70	-	dB
Zi	input impedance	input referenced to ground	40	60	90	kΩ
Quad SE ap	oplication (see Fig.8)				-	
THD	total harmonic distortion	$f_i = 1 \text{ kHz}; P_o = 1 \text{ W}; R_L = 4 \Omega$	-	0.05	0.15	%
		$\begin{array}{l} \text{45 Hz} < \text{f}_{\text{i}} < \text{10 kHz}; \text{ P}_{\text{o}} = 1 \text{ W}; \\ \text{R}_{\text{L}} = 4 \ \Omega; \text{ filter: } \text{f} < \text{30 kHz} \end{array}$	_	0.5	-	%
Po	output power	$V_{P} = 14.4 \text{ V}; \text{ R}_{L} = 4 \Omega; \text{ note } 2$				
		THD = 0.5%	4	4.5	_	W
		THD = 10%	5	6	_	W
G _v	voltage gain	V _{i(rms)} = 15 mV	25	26	27	dB
ΔG_v	channel unbalance	V _{i(rms)} = 15 mV	-0.7	0	+0.7	dB
α_{cs}	channel separation	$P_o = 2 W; f_i = 1 \text{ kHz}; R_L = 4 \Omega$	40	50	-	dB
V _{OO}	DC output offset voltage	$V_P = 14.4 V$; on condition	-	0	100	mV
		$V_P = 14.4 \text{ V}; \text{ R}_L = 4 \Omega;$ mute condition	_	10	20	mV
V _{n(o)}	noise output voltage on	$R_s = 1 k\Omega; V_P = 14.4 V; note 3$	-	80	150	μV
V _{n(o)(mute)}	noise output voltage mute	note 3	-	0	20	μV
V _{o(mute)}	output voltage mute	V _{i(rms)} = 1 V	-	3	500	μV
SVRR	supply voltage ripple rejection					
		on condition	43	47	-	dB
		mute condition	55	70	-	dB

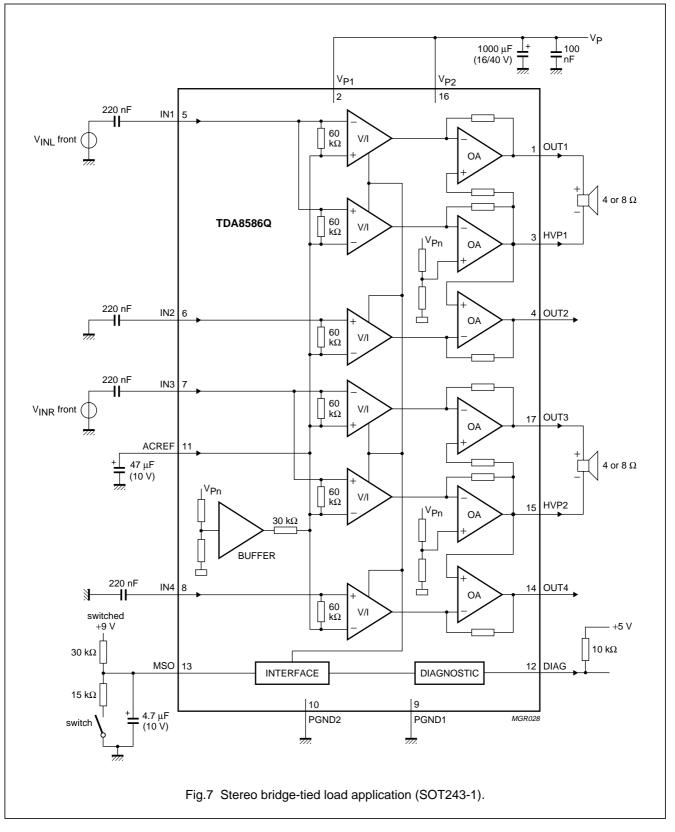
Notes

1. Tolerances on the mute level is tight because of the usage of this pin for integration during load detection.

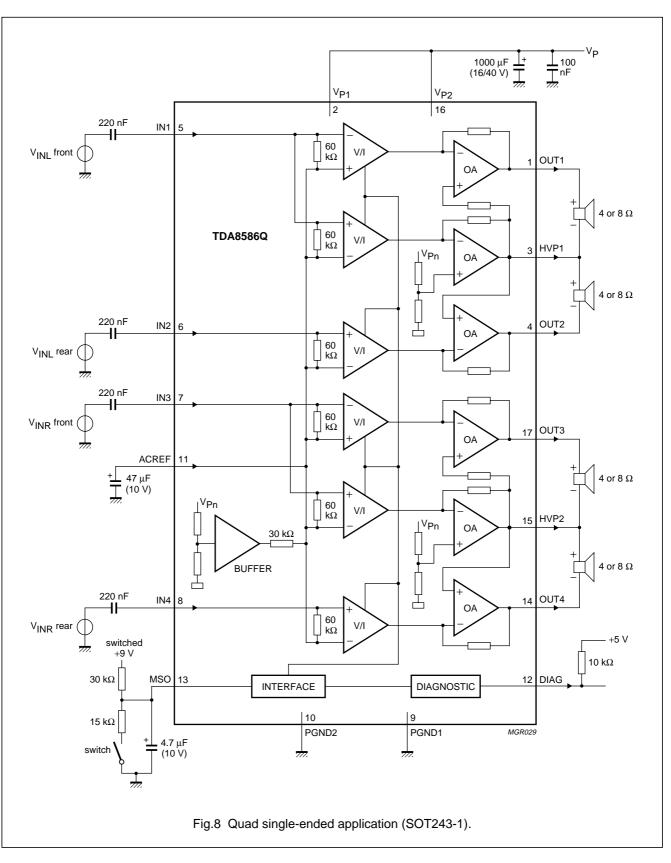
- 2. The output power is measured directly on the pins of the IC.
- 3. The noise output is measured in a bandwidth of 20 Hz to 20 kHz.

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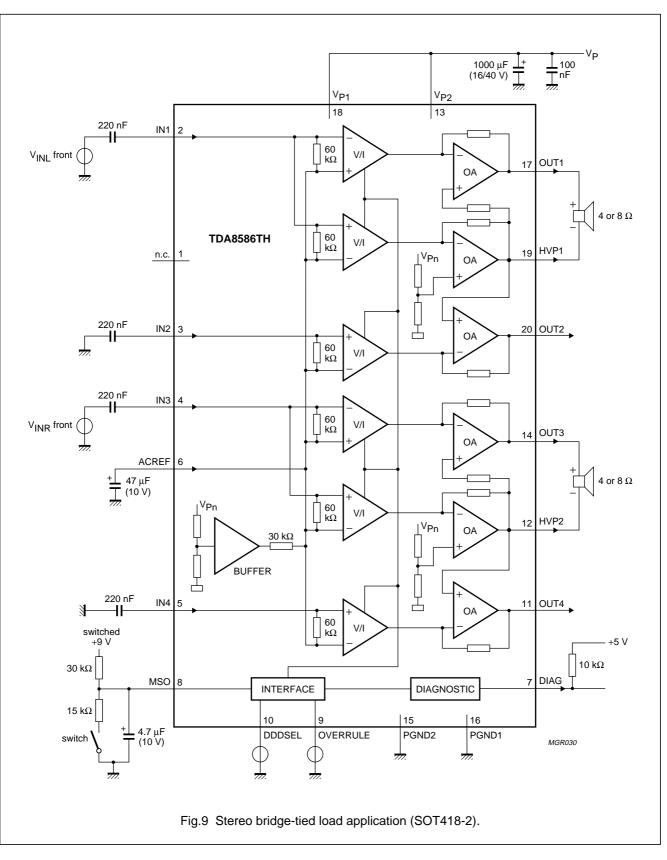
APPLICATION INFORMATION

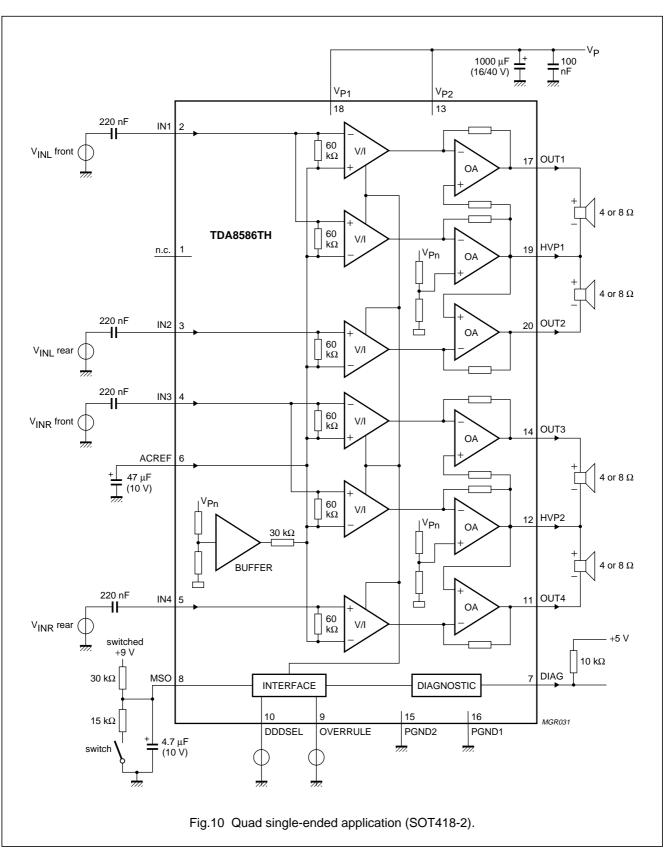


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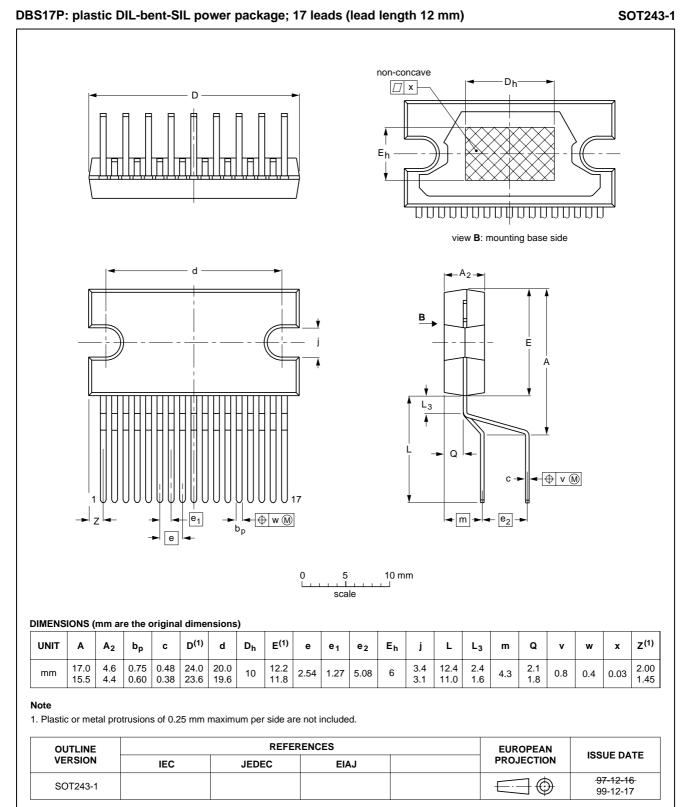
INTERNAL PIN CONFIGURATION

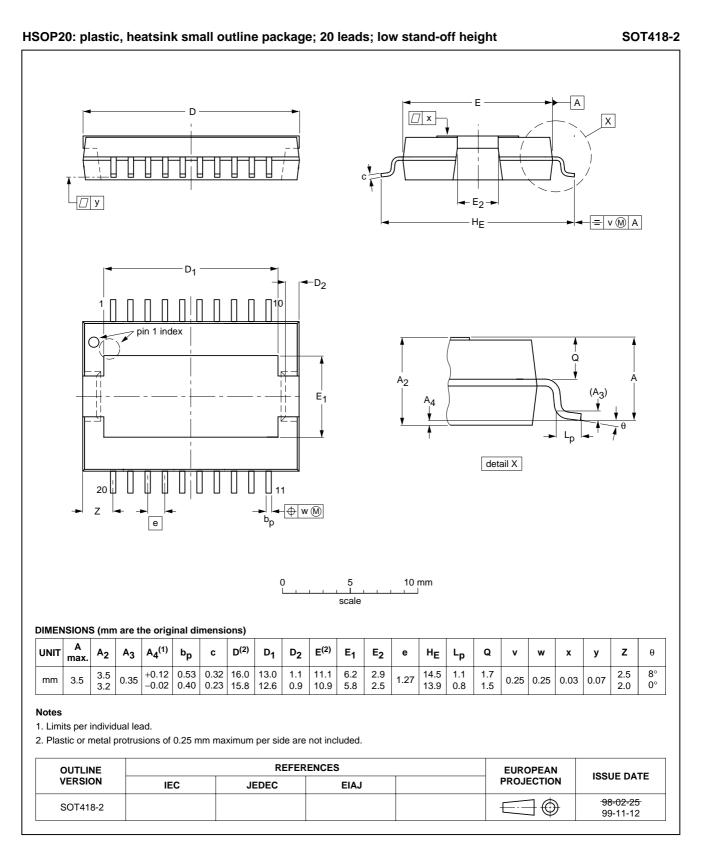
PIN TDA8586TH	NAME	EQUIVALENT CIRCUIT
2, 3, 4, 5 and 6	inputs	
11, 12, 14, 17, 19 and 20	outputs	VP O.5 VP MGE015
8	mode select	VP VP VP VP MGE016

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Power amplifier with load detection and auto BTL/SE selection

PACKAGE OUTLINES





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SOLDERING

Introduction

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mount components are mixed on one printed-circuit board. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

Through-hole mount packages

SOLDERING BY DIPPING OR BY SOLDER WAVE

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joints for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ($T_{stg(max)}$). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

MANUAL SOLDERING

Apply the soldering iron (24 V or less) to the lead(s) of the package, either below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

Surface mount packages

REFLOW SOLDERING

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method. Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferable be kept below 220 °C for thick/large packages, and below 235 °C for small/thin packages.

WAVE SOLDERING

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

• For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C. A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

MANUAL SOLDERING

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

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Suitability of IC packages for wave, reflow and dipping soldering methods

MOUNTING	PACKAGE	SOLDERING METHOD			
MOONTING	FACKAGE	WAVE	REFLOW ⁽¹⁾	DIPPING	
Through-hole mount	DBS, DIP, HDIP, SDIP, SIL	suitable ⁽²⁾	-	suitable	
Surface mount	BGA, HBGA, LFBGA, SQFP, TFBGA	not suitable	suitable	_	
	HBCC, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, HVQFN, SMS	not suitable ⁽³⁾	suitable	_	
	PLCC ⁽⁴⁾ , SO, SOJ	suitable	suitable	-	
	LQFP, QFP, TQFP	not recommended ⁽⁴⁾⁽⁵⁾	suitable	-	
	SSOP, TSSOP, VSO	not recommended ⁽⁶⁾	suitable	_	

Notes

- 1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- 2. For SDIP packages, the longitudinal axis must be parallel to the transport direction of the printed-circuit board.
- 3. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
- 4. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- 5. Wave soldering is only suitable for LQFP, QFP and TQFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- 6. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

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DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

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